- **State-of-the-Art *EPIC*-II*B*™ BiCMOS Design Significantly Reduces Power Dissipation**

- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)**

- **Latch-Up Performance Exceeds 500 mA Per JESD 17**

- **Typical V_{OLP} (Output Ground Bounce) < 1 V at V_{CC} = 5 V, T_A = 25°C**

- **High-Drive Outputs (–32-mA I_{OH}, 64-mA I_{OL})**

- **Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), and Plastic (N) and Ceramic (J) DIPs**

SN54ABT620 . . . J PACKAGE
SN74ABT620 . . . DB, DW, N, OR PW PACKAGE
(TOP VIEW)

OEAB	1	20	V_{CC}
A1	2	19	$\overline{OEBA}$
A2	3	18	B1
A3	4	17	B2
A4	5	16	B3
A5	6	15	B4
A6	7	14	B5
A7	8	13	B6
A8	9	12	B7
GND	10	11	B8

SN54ABT620 . . . FK PACKAGE
(TOP VIEW)

Top pins: A2 (3), A1 (2), OEAB (1), V_{CC} (20), $\overline{OEBA}$ (19)

A3	4	18	B1
A4	5	17	B2
A5	6	16	B3
A6	7	15	B4
A7	8	14	B5

Bottom pins: A8 (9), GND (10), B8 (11), B7 (12), B6 (13)

description

These octal bus transceivers provide for asynchronous communication between data buses. The control-function implementation allows for maximum flexibility in timing. The 'ABT620 devices provide inverted data at the outputs.
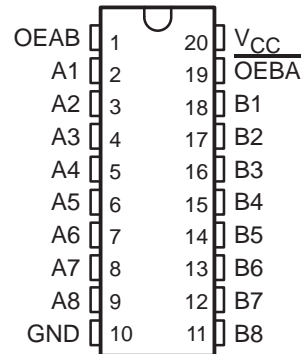
These devices allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic levels at the output-enable (OEAB and $\overline{OEBA}$) inputs.

The output-enable inputs can be used to disable the device so that the buses are effectively isolated. The dual-enable configuration gives the transceivers the capability of storing data by simultaneously enabling OEAB and $\overline{OEBA}$. When both OEAB and $\overline{OEBA}$ are enabled and all other data sources to the two sets of bus lines are at high impedance, both sets of bus lines (16 total) remain at their last states. In this way, each output reinforces its input in this configuration.
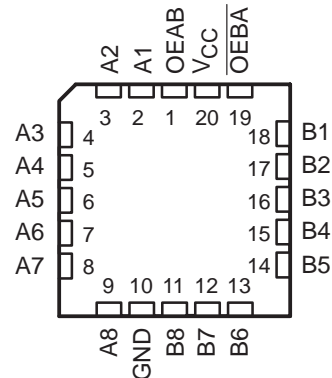
To ensure the high-impedance state during power up or power down, $\overline{OEBA}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver. OEAB should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

The SN54ABT620 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ABT620 is characterized for operation from –40°C to 85°C.

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FUNCTION TABLE

INPUTS		OPERATION
$\overline{\text{OEBA}}$	OEAB	
L	L	$\overline{\text{B}}$ data to A bus
L	H	$\overline{\text{B}}$ data to A bus, $\overline{\text{A}}$ data to B bus
H	L	Isolation
H	H	$\overline{\text{A}}$ data to B bus

logic symbol†
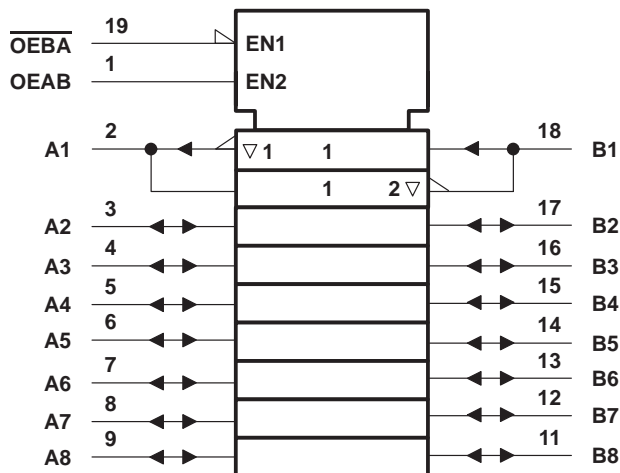
logic diagram (positive logic)

To Seven Other Channels
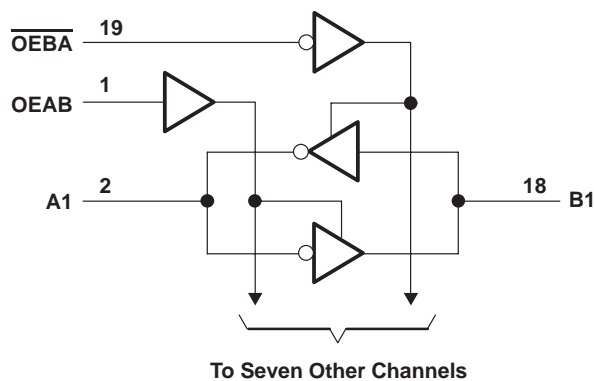
† This symbol is in accordance with ANSI/IEEE Std 91-1984 and
IEC Publication 617-12.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V_{CC} .... −0.5 V to 7 V
Input voltage range, V_I (see Note 1) .... −0.5 V to 7 V
Voltage range applied to any output in the high or power-off state, V_O .... −0.5 V to 5.5 V
Current into any output in the low state, I_O: SN54ABT620 .... 96 mA
SN74ABT620 .... 128 mA
Input clamp current, I_{IK} (V_I < 0) .... −18 mA
Output clamp current, I_{OK} (V_O < 0) .... −50 mA
Package thermal impedance, θ_{JA} (see Note 2): DB package .... 115°C/W
DW package .... 97°C/W
N package .... 67°C/W
PW package .... 128°C/W
Storage temperature range, T_{stg} .... −65°C to 150°C

‡ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and
functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not
implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
NOTES: 1.   The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2.   The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace
length of zero.

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recommended operating conditions (see Note 3)

			SN54ABT620		SN74ABT620		UNIT
			MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage		4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage		2		2		V
V_{IL}	Low-level input voltage			0.8		0.8	V
V_I	Input voltage		0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current			–24		–32	mA
I_{OL}	Low-level output current			48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		5		5	ns/V
T_A	Operating free-air temperature		–55	125	–40	85	°C

NOTE 3: All unused pins (control or I/O) of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		$T_A = 25°C$			SN54ABT620		SN74ABT620		UNIT
				MIN	TYP†	MAX	MIN	MAX	MIN	MAX	
V_{IK}		$V_{CC} = 4.5$ V,	$I_I = -18$ mA			−1.2		−1.2		−1.2	V
V_{OH}		$V_{CC} = 4.5$ V,	$I_{OH} = -3$ mA	2.5			2.5		2.5		V
		$V_{CC} = 5$ V,	$I_{OH} = -3$ mA	3			3		3		
		$V_{CC} = 4.5$ V	$I_{OH} = -24$ mA	2			2				
			$I_{OH} = -32$ mA	2*					2		
V_{OL}		$V_{CC} = 4.5$ V	$I_{OL} = 48$ mA			0.55		0.55			V
			$I_{OL} = 64$ mA			0.55*				0.55	
V_{hys}					100						mV
I_I	Control inputs	$V_{CC} = 5.5$ V,	$V_I = V_{CC}$ or GND			±1		±1		±1	µA
	A or B ports					±100		±100		±100	
I_{OZH}‡		$V_{CC} = 5.5$ V,	$V_O = 2.7$ V			50		50		50	µA
I_{OZL}‡		$V_{CC} = 5.5$ V,	$V_O = 0.5$ V			−50		−50		−50	µA
I_{off}		$V_{CC} = 0$,	V_I or $V_O ≤ 4.5$ V			±100				±100	µA
I_{CEX}		$V_{CC} = 5.5$ V, $V_O = 5.5$ V	Outputs high			50		50		50	µA
I_O§		$V_{CC} = 5.5$ V,	$V_O = 2.5$ V	−50	−100	−180	−50	−180	−50	−180	mA
I_{CC}	A or B ports	$V_{CC} = 5.5$ V, $I_O = 0$, $V_I = V_{CC}$ or GND	Outputs high		5	250		250		250	µA
			Outputs low		24	30		30		30	mA
			Outputs disabled		0.5	250		250		250	µA
ΔI_{CC}¶	Data inputs	$V_{CC} = 5.5$ V, One input at 3.4 V, Other inputs at V_{CC} or GND	Outputs enabled			1.5		1.5		1.5	mA
			Outputs disabled			0.05		0.05		0.05	
	Control inputs	$V_{CC} = 5.5$ V, One input at 3.4 V, Other inputs at V_{CC} or GND				1.5		1.5		1.5	
C_i	Control inputs	$V_I = 2.5$ V or 0.5 V			4						pF
C_{io}	A or B ports	$V_O = 2.5$ V or 0.5 V			7						pF

* On products compliant to MIL-PRF-38535, this parameter does not apply.
† All typical values are at $V_{CC} = 5$ V.
‡ The parameters I_{OZH} and I_{OZL} include the input leakage current.
§ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
¶ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 5 V, T_A = 25°C		SN54ABT620		SN74ABT620		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A or B	B or A	1	4.1	1		1	4.8	ns
t_{PHL}			1	4.3	1		1	4.8	
t_{PZH}	$\overline{OEBA}$	A	1.3	4.6	1.3		1.3	5.5	ns
t_{PZL}			1	6.1	1		1	7.1	
t_{PHZ}	$\overline{OEBA}$	A	2	6.3	2		2	7	ns
t_{PLZ}			1.4	5.4	1.4		1.4	5.8	
t_{PZH}	OEAB	B	1.6	6.2	1.6		1.6	6.8	ns
t_{PZL}			2	5.9	2		2	6.4	
t_{PHZ}	OEAB	B	1.2	5.6	1.2		1.2	6.5	ns
t_{PLZ}			1.1	4.7	1.1		1.1	5.6	

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PARAMETER MEASUREMENT INFORMATION
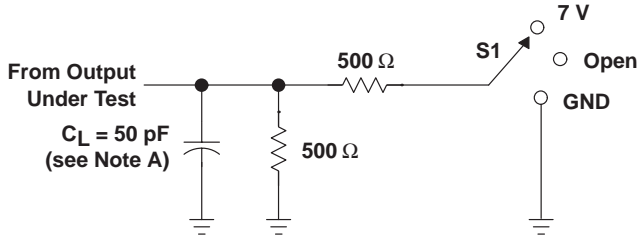
LOAD CIRCUIT

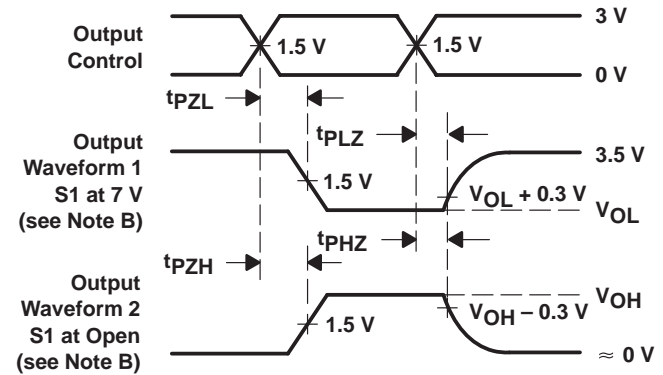| TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	7 V
t_{PHZ}/t_{PZH}	Open
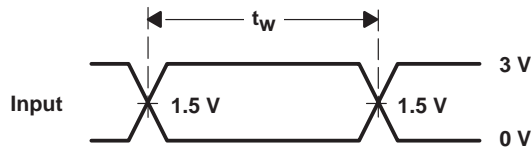
VOLTAGE WAVEFORMS
PULSE DURATION
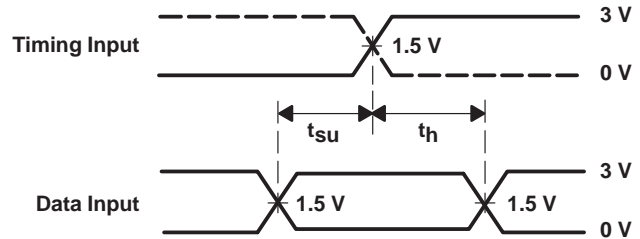
VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES
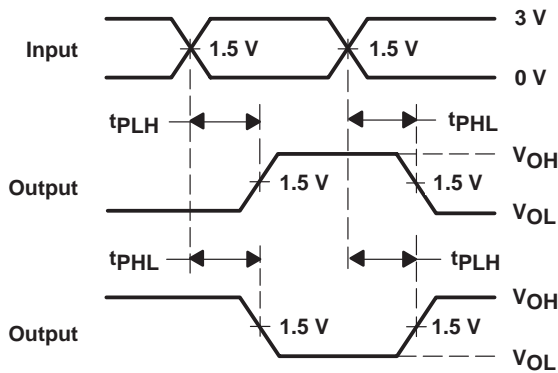
VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS

VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

NOTES: A. C_L includes probe and jig capacitance.
  B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
    Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.
  D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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